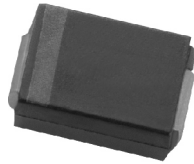


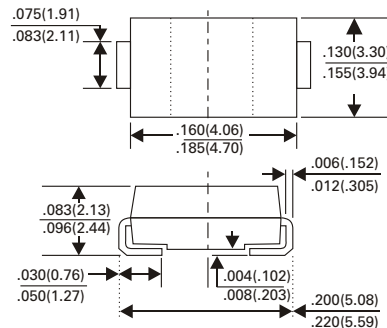
ES1AB thru ES1JB

SURFACE MOUNT SUPERFAST RECTIFIER

VOLTAGE - 50 TO 600 VOLTS CURRENT - 1.0 AMPERES



SMB/DO-214AA



Dimensions in inches and (millimeters)

FEATURES

- For surface mount applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Superfast recovery times for high efficiency
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated junction
- High temperature soldering : 260°C/10seconds at terminals
- Pb free product are available : 99% Sn above can meet RoHS Environment substance directive request

MECHANICAL DATA

Case : JEDEC DO-214AA molded plastic
 Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
 Polarity : Indicated by cathode band
 Standard packaging : 16mm tape (EIA-481)
 Weight : 0.003 ounce, 0.093grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified
 Single phase, half wave, 60Hz, resistive or inductive load
 For capacitive load, derate current by 20%

	SYMBOL	ES1AB	ES1BB	ES1CB	ES1DB	ES1EB	ES1GB	ES1JB	UNITS
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	Volts
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	420	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	Volts
Maximum Average Forward Rectified Current @ $T_L = 100^\circ\text{C}$	$I_{(AV)}$	1.0							Amps
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	30							Amps
Maximum Instantaneous Forward Voltage at 1.0A	V_F	0.95			1.25		1.7		Volts
Maximum DC Reverse Current @ $T_J = 25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_J = 100^\circ\text{C}$	I_R	5.0 / 100							μA
Maximum Reverse Recovery Time (NOTE 1)	T_{RR}	35							nS
Typical Junction Capacitance (NOTE 2)	C_J	10							pF
Typical Thermal Resistance (NOTE 3)	$R_{\theta JA}$	34							$^\circ\text{C} / \text{W}$
Operating and Storage Temperature Range	T_J T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES :

1. Reverse Recovery Test Conditions $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{RR} = 0.25\text{A}$
2. Measured at 1 MHz and applied reverse Voltage of 4.0VDC
3. 8.0mm^2 (.013mm thick) land areas

ES1AB thru ES1JB

SURFACE MOUNT SUPERFAST RECTIFIER

RATING AND CHARACTERISTICS CURVES ES1AB THRU ES1JB

Fig. 1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM ES1A THRU ES1G

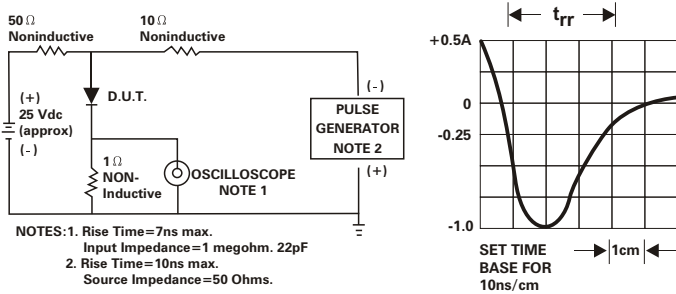


Fig. 2 - MAXIMUM AVERAGE FORWARD CURRENT RATING

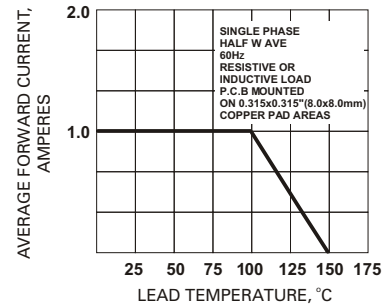


Fig. 3 - TYPICAL REVERSE CHARACTERISTICS

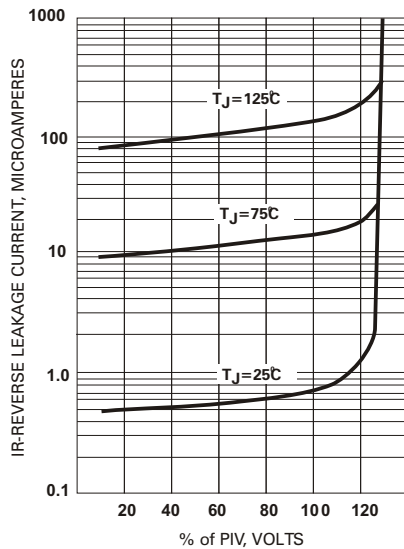


Fig. 4 - TYPICAL FORWARD CHARACTERISTICS

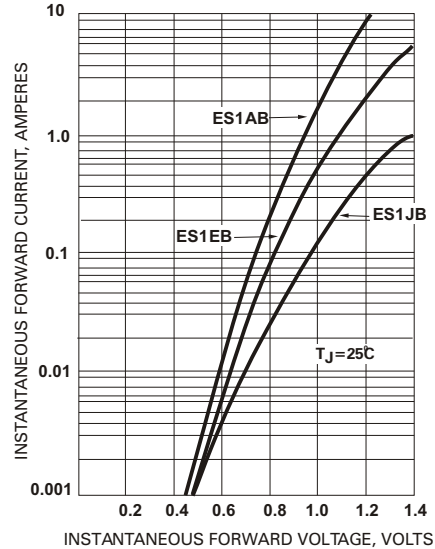


Fig. 5 - MAXIMUM NON-REPETITIVE SURGE CURRENT

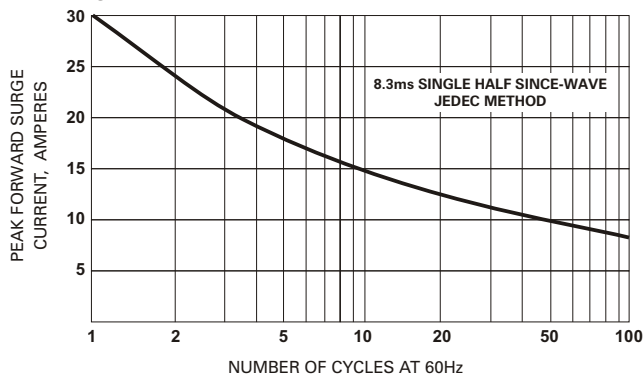


Fig. 6 - TYPICAL JUNCTION CAPACITANCE

